Silicon P Channel MOS FET High Speed Power Switching

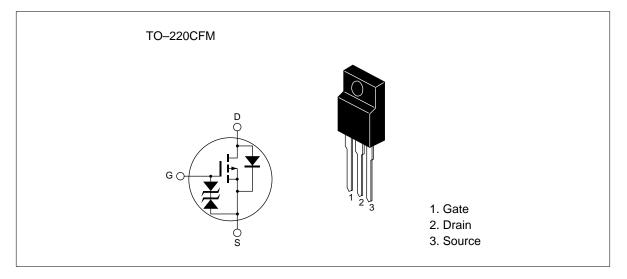
# HITACHI

ADE-208-638A (Z) 2nd. Edition Jun 1998

#### Features

- Low on-resistance  $R_{DS(on)} = 0.075\Omega$  typ.
- Low drive current.
- 4V gate drive devices.
- High speed switching.

## Outline





# **Absolute Maximum Ratings** (Ta = $25^{\circ}$ C)

Item	Symbol	Ratings	Unit	
Drain to source voltage	V <sub>DSS</sub>	-60	V	
Gate to source voltage	V <sub>GSS</sub>	±20	V	
Drain current	I <sub>D</sub>	-15	A	
Drain peak current	Note1 D(pulse)	-60	А	
Body-drain diode reverse drain current	I <sub>DR</sub>	-15	A	
Avalanche current	AP Note3	-15	A	
Avalanche energy	E <sub>AR</sub> <sup>Note3</sup>	19	mJ	
Channel dissipation	Pch <sup>Note2</sup>	30	W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Note: 1.  $PW \le 10\mu s$ , duty cycle  $\le 1 \%$ 

2. Value at Tc =  $25^{\circ}C$ 

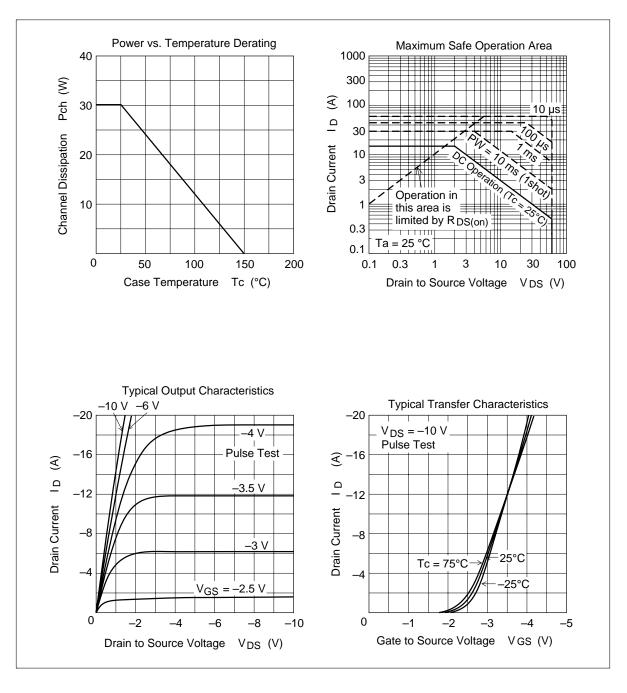
3. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

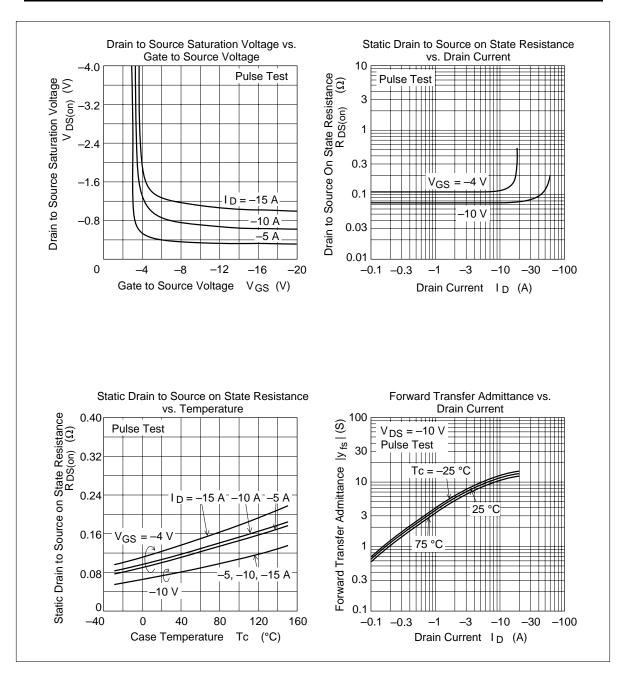
## **Electrical Characteristics** (Ta = 25°C)

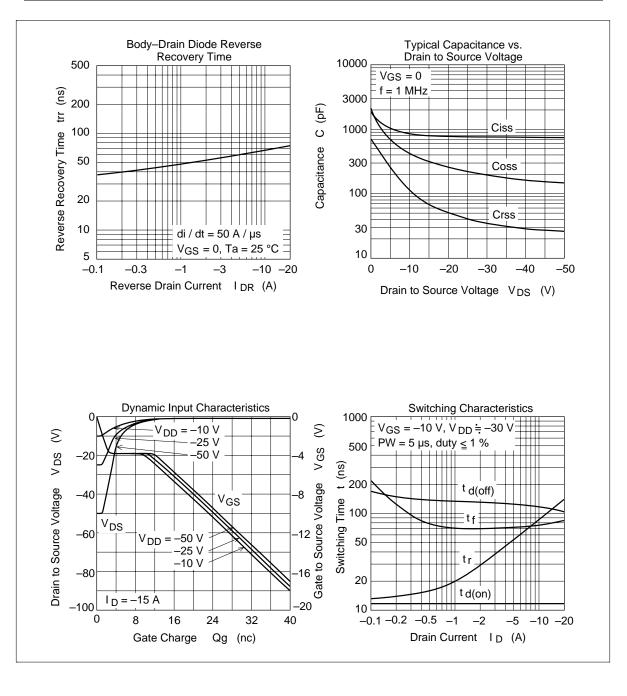
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	e V <sub>(BR)DSS</sub>	-60	_	_	V	$I_{\rm D} = -10 {\rm mA}, V_{\rm GS} = 0$
Gate to source breakdown voltage	V <sub>(BR)GSS</sub>	±20			V	$I_{g} = \pm 100 \mu A, V_{DS} = 0$
Zero gate voltege drain current	I <sub>DSS</sub>			-10	μA	$V_{\rm DS} = -60 \ V, \ V_{\rm GS} = 0$
Gate to source leak current	I <sub>GSS</sub>			±10	μA	$V_{GS} = \pm 16V, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0	_	-2.0	V	$I_{\rm D} = -1$ mA, $V_{\rm DS} = -10$ V
Static drain to source on state	R <sub>DS(on)</sub>		0.075	0.095	Ω	$I_{\rm D} = -8A, V_{\rm GS} = -10V^{\rm Note4}$
resistance	R <sub>DS(on)</sub>		0.105	0.155	Ω	$I_{\rm D} = -8A, V_{\rm GS} = -4V^{\rm Note4}$
Forward transfer admittance	y <sub>fs</sub>	6.5	11	_	S	$I_{\rm D} = -8A, V_{\rm DS} = 10V^{\rm Note4}$
Input capacitance	Ciss	_	850	_	pF	$V_{DS} = -10V$
Output capacitance	Coss		420	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss		110	_	pF	f = 1MHz
Turn-on delay time	t <sub>d(on)</sub>		12		ns	$V_{\rm GS} = -10V, I_{\rm D} = -8A$
Rise time	t,		75	_	ns	$R_{L} = 3.75\Omega$
Turn-off delay time	$t_{d(off)}$		125	_	ns	_
Fall time	t <sub>f</sub>	_	75	_	ns	_
Body-drain diode forward voltage	V <sub>DF</sub>	_	-1.1	_	V	$I_{\rm F} = -15 {\rm A}, V_{\rm GS} = 0$
Body–drain diode reverse recovery time	t <sub>rr</sub>	_	70	_	ns	$I_{F} = -15A, V_{GS} = 0$ diF/ dt =50A/ $\mu$ s
Noto: A Dulas test						

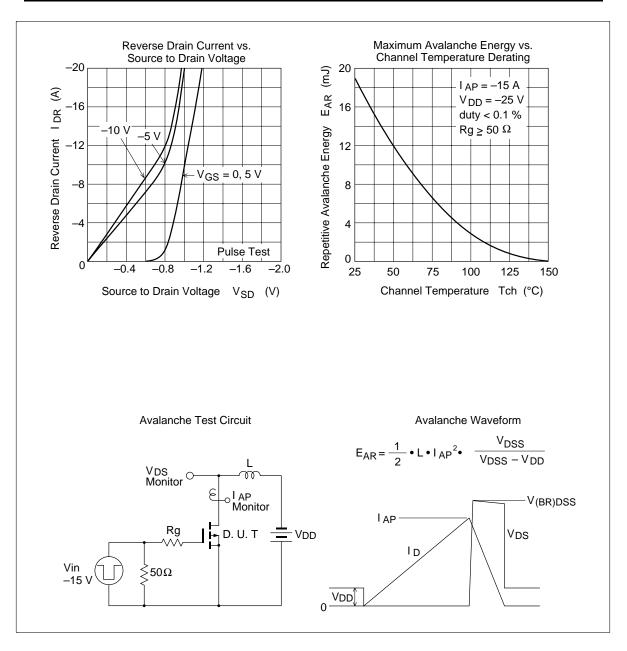
Note: 4. Pulse test

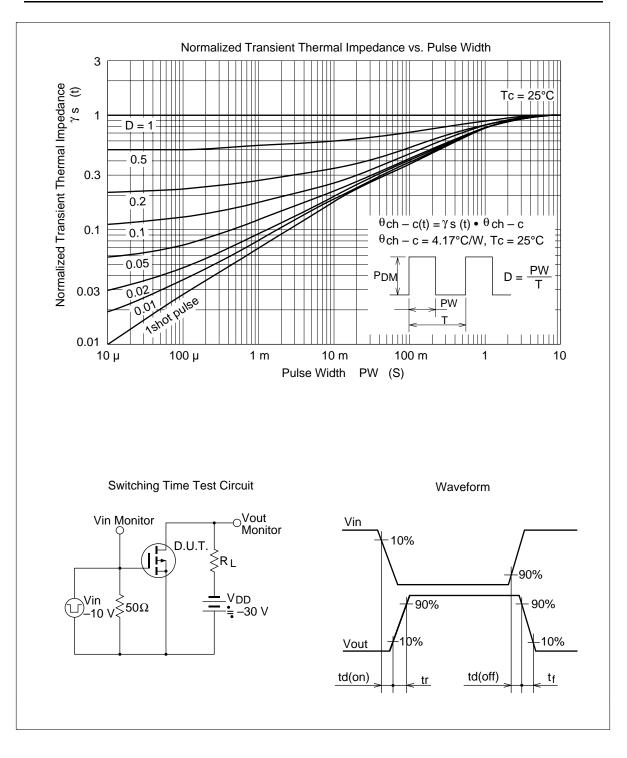
#### **Main Characteristics**





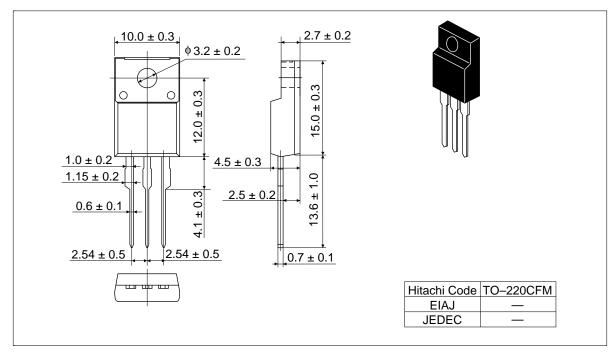






# **Package Dimensions**

Unit: mm



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